

MCC

Micro Commercial Components
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**BC546,B
BC547,A,B,C
BC548,A,B,C**

Features

- Through Hole Package
- 150°C Junction Temperature

Pin Configuration
Bottom View



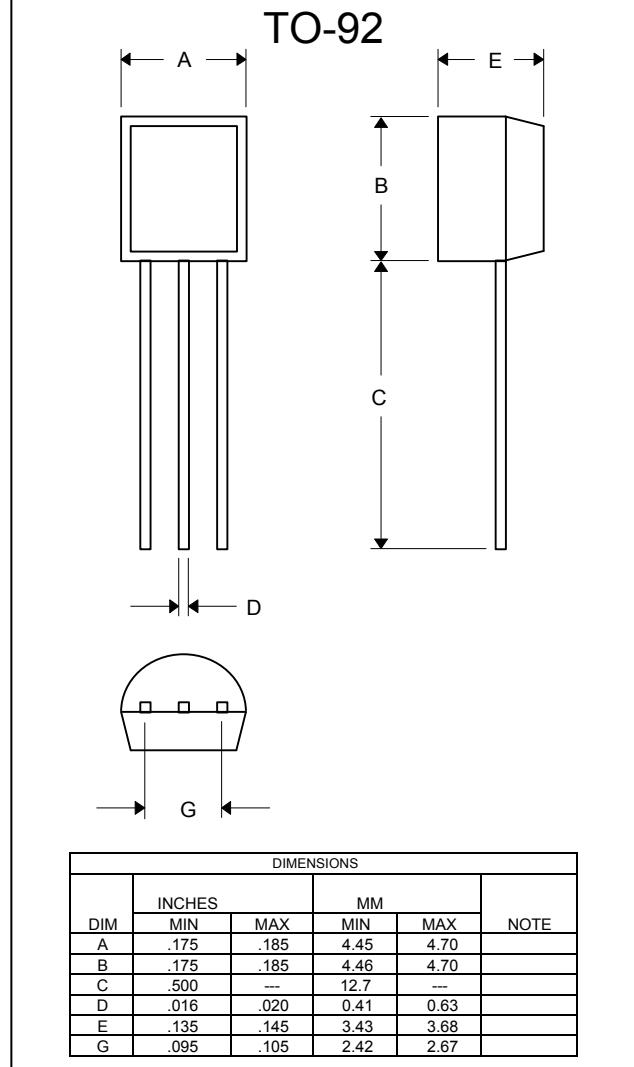
Mechanical Data

- Case: TO-92, Molded Plastic
- Polarity: indicated as above.

Maximum Ratings @ 25°C Unless Otherwise Specified

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	65	
		45	V
		30	
Collector-Base Voltage	V_{CBO}	80	
		50	V
		30	
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current(DC)	I_C	100	mA
Power Dissipation@ $T_A=25^\circ\text{C}$	P_d	625 5.0	mW $\text{mW}/^\circ\text{C}$
Power Dissipation@ $T_C=25^\circ\text{C}$	P_d	1.5 12	W $\text{mW}/^\circ\text{C}$
Thermal Resistance, Junction to Ambient Air	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$
Operating & Storage Temperature	T_i, T_{STG}	-55~150	$^\circ\text{C}$

**NPN Silicon
Amplifier Transistor
625mW**



BC546 thru BC548C

MCC

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage ($I_C = 1.0 \text{ mA}, I_B = 0$)	$V_{(\text{BR})\text{CEO}}$	65 45 30	— — —	— — —	V
Collector-Base Breakdown Voltage ($I_C = 100 \mu\text{A}$)	$V_{(\text{BR})\text{CBO}}$	80 50 30	— — —	— — —	V
Emitter-Base Breakdown Voltage ($I_E = 10 \mu\text{A}, I_C = 0$)	$V_{(\text{BR})\text{EBO}}$	6.0 6.0 6.0	— — —	— — —	V

ON CHARACTERISTICS

DC Current Gain ($I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$)	BC547A/548A BC546B/547B/548B BC548C	h_{FE}	— — —	90 150 270	— — —	—
($I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$)	BC546 BC547 BC548 BC547A/548A BC546B/547B/548B BC547C/BC548C		110 110 110 110 200 420	— — — 180 290 520	450 800 800 220 450 800	
($I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}$)	BC547A/548A BC546B/547B/548B BC548C		— — —	120 180 300	— — —	
Collector-Emitter Saturation Voltage ($I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$)	$V_{CE(\text{sat})}$		—	---	0.3	V
Base-Emitter Saturation Voltage ($I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$)	$V_{BE(\text{sat})}$		—	—	1.0	V
Base-Emitter On Voltage ($I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$) ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$)	$V_{BE(\text{on})}$		0.55 —	— —	0.7 0.77	V

SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz}$)	BC546 BC547 BC548	f_T	150 150 150	300 300 300	— — —	MHz
Output Capacitance ($V_{CB} = 10 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$)		C_{obo}	—	1.7	4.5	pF
Input Capacitance ($V_{EB} = 0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$)		C_{ibo}	—	10	—	pF
Small-Signal Current Gain ($I_C = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ kHz}$)	BC546 BC547/548 BC547A/548A BC546B/547B/548B BC547C/548C	h_{fe}	125 125 125 240 450	— — 220 330 600	500 900 260 500 900	—
Noise Figure ($I_C = 0.2 \text{ mA}, V_{CE} = 5.0 \text{ V}, R_S = 2 \text{ k}\Omega, f = 1.0 \text{ kHz}, \Delta f = 200 \text{ Hz}$)	BC546 BC547 BC548	NF	— — —	2.0 2.0 2.0	10 10 10	dB

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BC546 thru BC548C

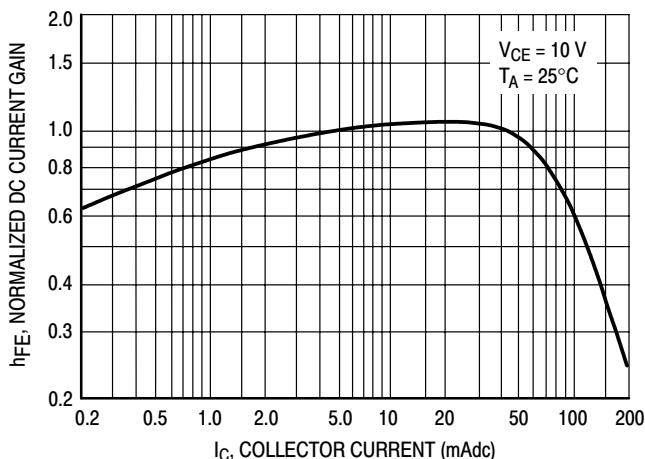


Figure 1. Normalized DC Current Gain

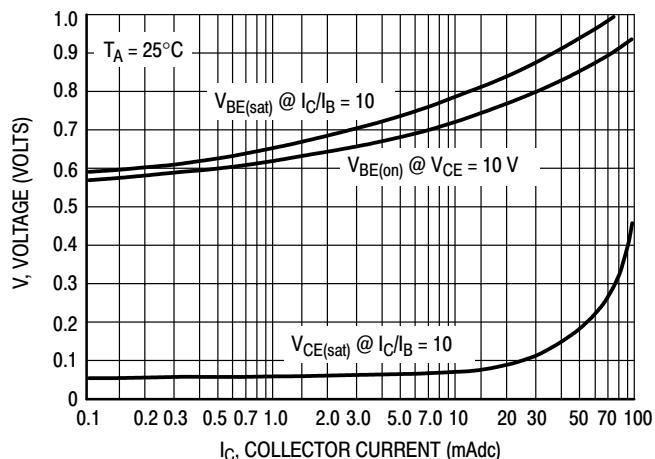


Figure 2. "Saturation" and "On" Voltages

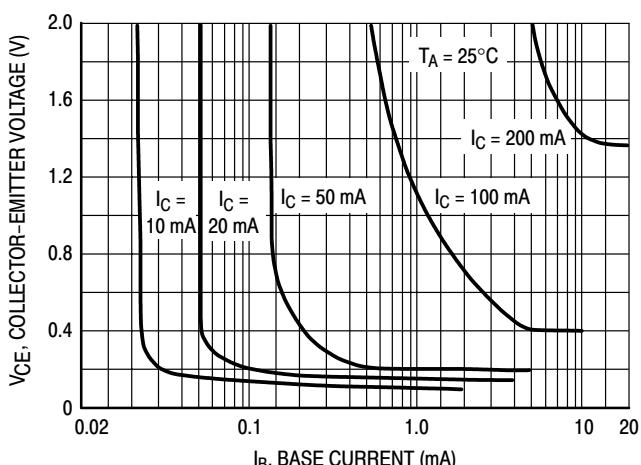


Figure 3. Collector Saturation Region

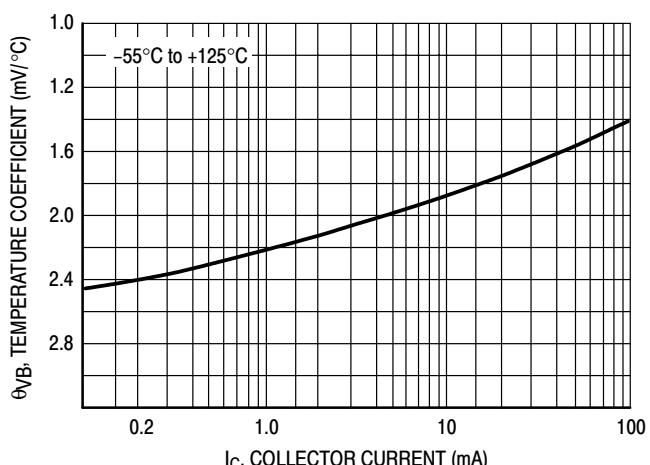


Figure 4. Base-Emitter Temperature Coefficient

BC547/BC548

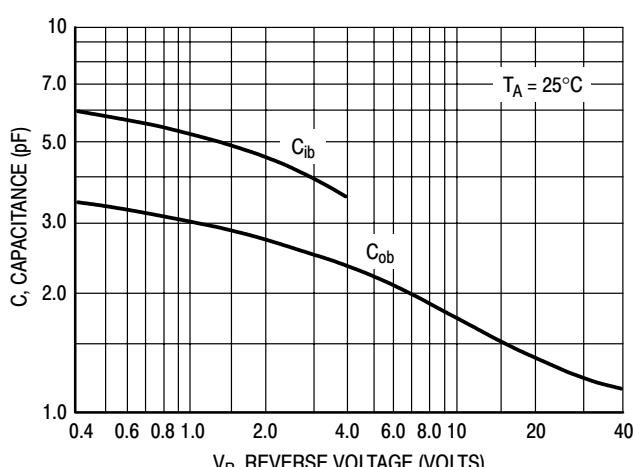


Figure 5. Capacitances

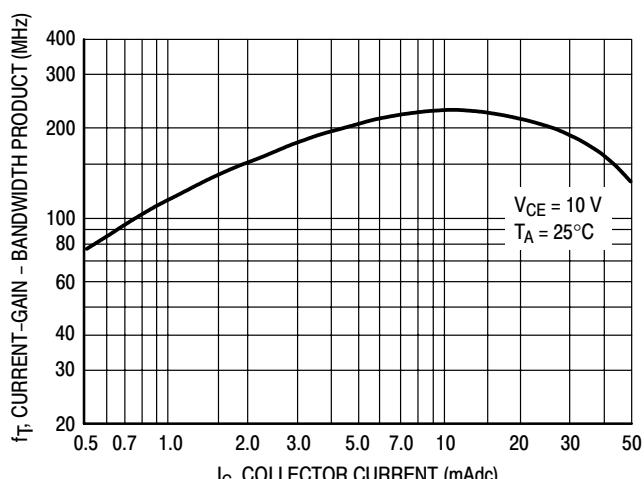


Figure 6. Current-Gain - Bandwidth Product

BC546 thru BC548C

BC547/BC548

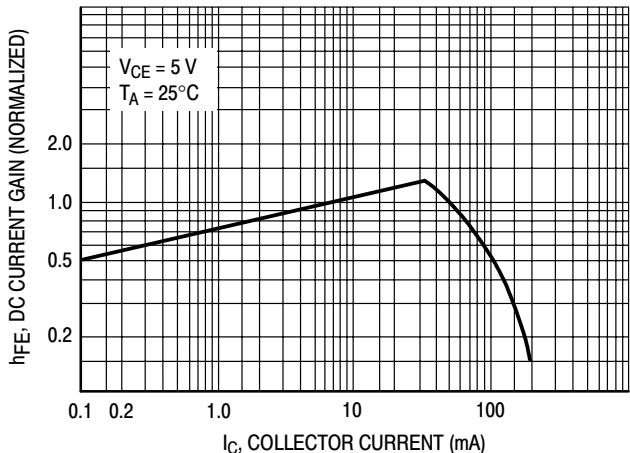


Figure 7. DC Current Gain

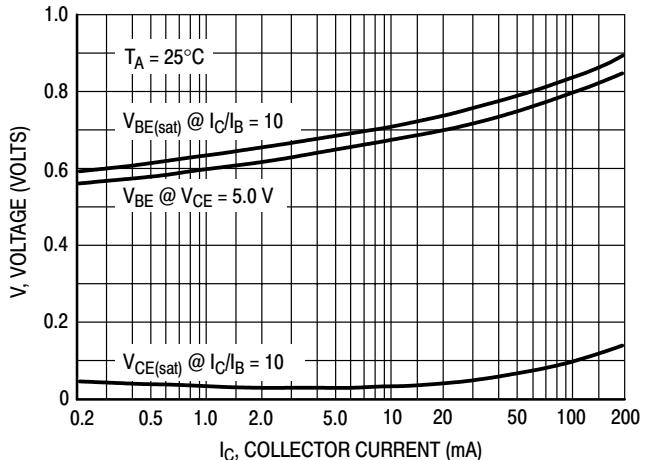


Figure 8. "On" Voltage

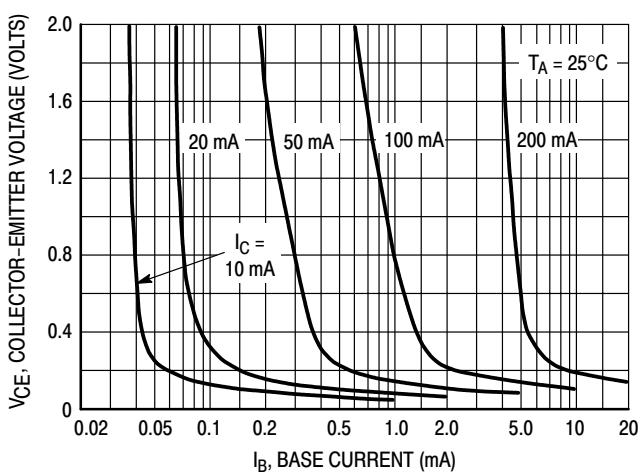


Figure 9. Collector Saturation Region

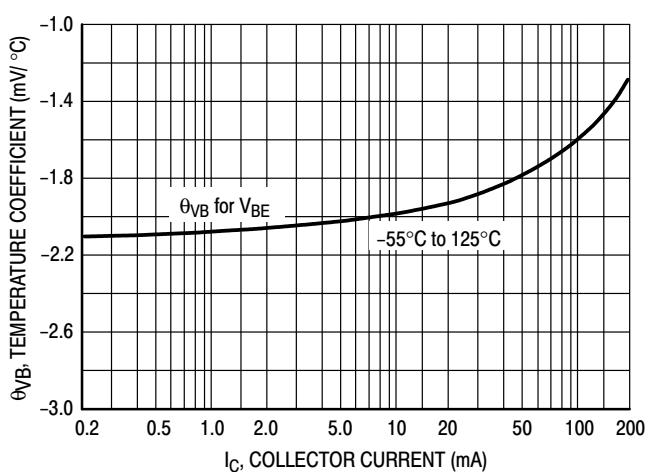


Figure 10. Base-Emitter Temperature Coefficient

BC546

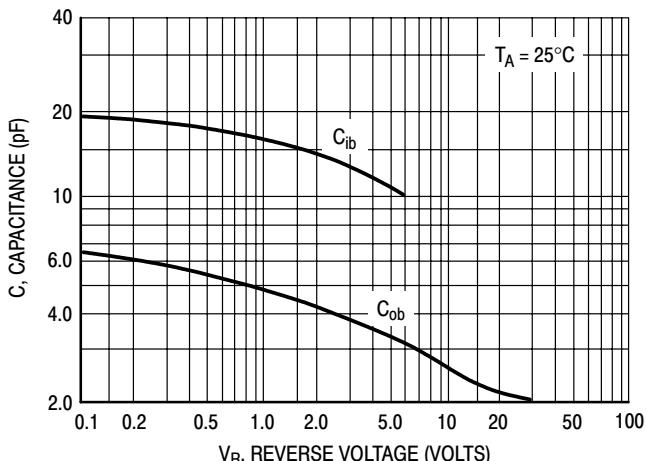


Figure 11. Capacitance

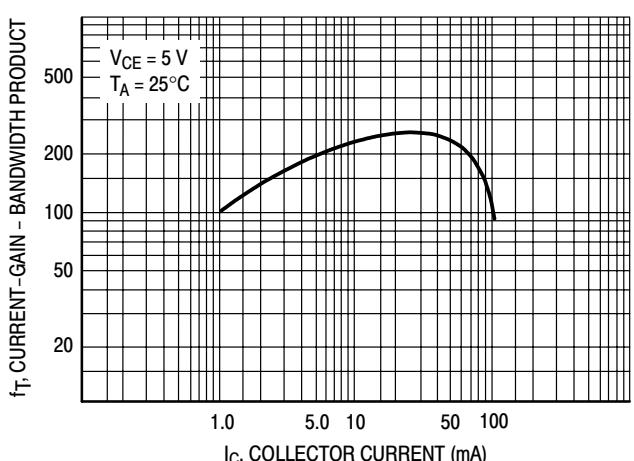


Figure 12. Current-Gain – Bandwidth Product